

Metal Composite Power Inductor (Thin Film)

Specification Sheet



Unit : mm

2520

1.2

0.8

2.0

TYPE

A

В

С

CIGT252012LM2R2MNE (2520 / EIA 1008)

Smart phones, Tablet, Wearable devices, Power converter modules, etc.

Small power inductor for mobile devices Low DCR structure and high efficiency inductor for power circuits. Monolithic structure for high reliability Free of all RoHS-regulated substances Halogen free



TYPE		Dimension [mm]						
TIFE	Ľ	W	Т	D				
2520	2.5±0	0.2 2.0±0.2	1.2 max	0.55±0.25				

Part no.	Size Thickness [inch/mm] [mm] (max)	Inductance [uH]	Inductance tolerance (%)	DC Resistance [mΩ]		Rated DC Current (Isat) [A]		Rated DC Current (Irms) [A]		
				Max.	Тур.	Max.	Тур.	Max.	Тур.	
CIGT252012LM2R2MNE	1008/2520	1.2	2.2	±20	89	70	2.1	2.3	2	2.2

* Inductance : Measured with a LCR meter 4991A(Agilent) or equivalent (Test Freq. 1MHz, Level 0.1V)

* DC Resistance : Measured with a Resistance HI-TESTER 3541(HIOKI) or equivalent

* Maximum allowable DC current : Value defined when DC current flows and the initial value of inductance has decreased by 30% or

when current flows and temperature has risen to 40°C whichever is smaller. (Reference: ambient temperature is 25°C±10) (Isat) : Allowable current in DC saturation : The DC saturation allowable current value is specified when the decrease of

the initial inductance value at 30% (Reference: ambient temperature is 25°C±10)

(Irms) : Allowable current of temperature rise : The temperature rise allowable current value is specified when temperature of the inductor is raised 40°C by DC current. (Reference: ambient temperature is 25°C±10)

* Absolute maximum voltage : Absolute maximum voltage DC 20V.

* Operating temperature range : -40 to +125°C (Including self-temperature rise)

<u>CIG</u>	I	<u>2520</u>	<u>12</u>	LM	<u>2R2</u>	M	<u>N</u>	<u>E</u>
(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)

(2) Type

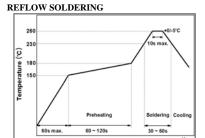
(4) Thicknes (12: 1.2mm)

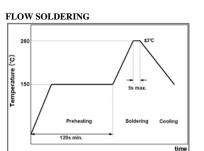
(6) Inductan (2R2: 2.2 uH)

(1) Power Inductor

- (3) Dimensior (2520: 2.5mm × 2.0mm)
- (5) Remark (Characterization Code)
- (7) Toleranc (M:±20%)
- (8) Internal Code
- (9) Packaging (C:paper tape, E:embossed tape)

RECOMMENDED SOLDERING CONDITION





IRON SOLDERING			
Temperature of	280°C max.		
Soldering Iron Tip	280 C max.		
Preheating	150°C min.		
Temperature	130 Cmin.		
Temperature	ΔT≤130℃		
Differential	$\Delta 1 \simeq 150 \text{ C}$		
Soldering Time	3sec max.		
	5500 max.		
Wattage	50W max.		

(T: Metal Composite Thin Film Type)

Packaging Style	Quantity(pcs/reel)		
Embossed Taping	2500 pcs		

TYPE	Dimension [mm]							
ITFE	L	W	Т	C				
2520	2.5±0.2	2.0±0.2	1.2 max	0.55±				

в

RECOMMENDED LAND PATTERN

в

Α

Item	Specified Value	٢	Fest Condition		
Solderability	More than 90% of terminal electrode should be soldered newly.		for 4±1 seconds, and preheated at , the specimen shall be immersed in seconds.		
Resistance to Soldering	No mechanical damage. Remaining terminal Electrode: 75% min. Inductance change to be within ±20% to the initial.	After being dipped in flux for 4±1 seconds, and preheated at $150 \sim 180^{\circ}$ C for 2 \sim 3 min, the specimen shall be immersed in solder at 260±5°C for 10 ±0.5 seconds.			
Thermal Shock (Temperature Cycle test)	No mechanical damage Inductance change to be within ±20% to the initial.	Repeat 100 cycles under the following conditions. -40±3 °C for 30 min → 85±3 °C for 30 min			
High Temp. Humidity Resistance Test	No mechanical damage Inductance change to be within ±20% to the initial	85±2℃, 85%RH, for 500: Measure the test items at humidity for 24 hours.	±12 hours. fter leaving at normal temperature and		
Low Temperature Test	No mechanical damage Inductance change to be within ±20% to the initial.	Solder the sample on PC at -55±2°C for 500±12 ho Measure the test items at humidity for 24hours.			
High Temperature Test	No mechanical damage Inductance change to be within ±20% to the initial.	hours.	B. Exposure at 125±2°C for 500±12 fter leaving at normal temperature and		
High Temp. Humidity Resistance Loading Test	No mechanical damage Inductance change to be within ±20% to the initial	85±2°C, 85%RH, Rated Current for 500±12 hours. Measure the test items after leaving at normal temperature and humidity for 24 hours.			
High Temperature Loading Test	No mechanical damage Inductance change to be within ±20% to the initial	85±2°C, Rated Current for 500±12 hours. Measure the test items after leaving at normal temperature and humidity for 24 hours.			
Reflow Test	No mechanical damage Inductance change to be within ±20% to the initial	Peak 260±5 °C, 3 times			
Vibration Test	No mechanical damage Inductance change to be within ±20% to the initial.	Solder the sample on PCB. Vibrate as apply 10~55Hz, 1.5mm amplitude for 2 hours in each of three(X,Y,Z) axis (total 6 hours).			
	No mechanical damage	Bending Limit; 2mm Test Speed; 1.0mm/sec. Keep the test board at the PCB thickness : 1.6mm	e limit point in 5 sec.		
Bending Test		20 R340 46	Unit :mm - <u>2</u>		
	No indication of peeling shall occur on the	W(kgf)	TIME(sec)		
	terminal electrode.	0.5	10±1		
Terminal Adhesion Test		77777 77777 77777			
Drop Test	No mechanical damage Inductance change to be within ±20% to the initial.	Random Free Fall test or 1 meter, 10 drops	n concrete plate.		



Data Sheet



1. Model : CIGT252012LM2R2MNE

2. Description

Part no.	Size Thickness		Inductance	Inductance tolerance (%)	DC Resistance [mΩ]		Rated DC Current (Isat) [A]		Rated DC Current (Irms) [A]	
	[inch/mm] [mm] (max)	Max.			Тур.	Max.	Тур.	Max.	Тур.	
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(Isat) : Allowable current in DC saturation : The DC saturation allowable current value is specified when the decrease of

the initial inductance value at 30% (Reference: ambient temperature is $25^\circ\!C\pm\!10$)

(Irms) : Allowable current of temperature rise : The temperature rise allowable current value is specified when temperature of

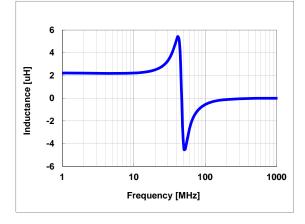
the inductor is raised 40 $^\circ C$ by DC current. (Reference: ambient temperature is 25 $^\circ C$ ±10)

* Absolute maximum voltage : Absolute maximum voltage DC 20V.

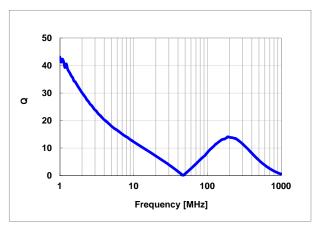
* Operating temperature range : -40 to +125°C (Including self-temperature rise)

3. Characteristics data

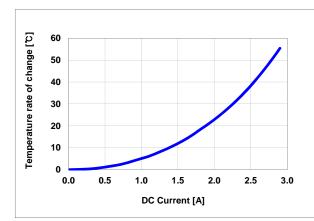
1) Frequency characteristics (Ls) Agilent E4294A +E4991A , 1MHz to 1,000MHz



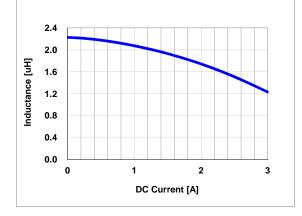
2) Frequency characteristics (Q) Agilent E4294A +E4991A , 1MHz to 1,000MHz



4)Temperature characteristics (Typ.)



3) DC Bias characteristics (Typ.)



Any data in this sheet are subject to change, modify or discontinue without notice The data sheets include the typical data for design reference only. If there is any question regarding the data sheets, please contact our sales personnel or application engineers